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Nonequilibrium characteristics in all-superconducting tunnel structures

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We study the nonequilibrium characteristics of superconducting tunnel structures in the case when one of the superconductors is a small island confined between large superconductors. The state of this island can be probed, for example, via the supercurrent flowing through it. We study both the far-from-equilibrium limit when the rate of injection for the electrons into the island exceeds the energy relaxation inside it, and the quasiequilibrium limit when the electrons equilibrate between themselves. We also address the crossover between these limits by employing the collision integral derived for the superconducting case. The clearest signatures of the nonequilibrium limit are the anomalous heating effects seen as a supercurrent suppression at low voltages, and the hysteresis at voltages close to the gap edge $2\Delta/e$, resulting from the peculiar form of the nonequilibrium distribution function.

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I. INTRODUCTION

New device concepts based on nonequilibrium effects in superconducting mesoscopic tunnel structures have been proposed in the last few years. These include Josephson transistors, electron refrigerators, and thermometers.^{1,2} In Josephson transistors the supercurrent flowing through a superconductor-normal metal-superconductor (SNS) weak link can be suppressed or even reversed in a π transition³⁻⁵ by driving the normal metal part out of equilibrium through injection of charge carriers from additional terminals. When the additional terminals are superconductors connected by tunnel junctions, the supercurrent can also be enhanced.⁶ This transistorlike operation with large current and power gain has also been experimentally demonstrated.⁷ Also, an all-superconducting SISIS transistor (where I represents an insulator) in the quasiequilibrium regime has been theoretically addressed.⁸ In the quasiequilibrium limit the electron-phonon interaction is nearly absent and the sample can be considered as detached from the phonon bath. The high frequency of electron-electron collisions still serves as a method of relaxation and the electrons assume a Fermi distribution but with a temperature that in general differs from the temperature of the phonon bath. Here we study a similar SISIS structure with arbitrary strength of the inelastic scattering, seeking ways to characterize the degree of nonequilibrium of the system. The paper is organized as follows. The model of the SISIS structure is presented in Sec. II. All the relevant equations and calculated results are presented in Secs. III and IV, respectively. We finish with a summary and a discussion in Sec. V, where we also address briefly the feasibility of this structure as a transistor.

II. MODEL

The superconducting structure under study is schematically depicted in Fig. 1. We characterize the mean free path that the electron travels before scattering by scattering lengths l_{el} for elastic scattering and l_{e-ph} and l_{e-e} for inelastic electron-phonon and electron-electron scattering, respec-

tively. In mesoscopic systems typical orders of magnitude are $l_{el} \approx 10-100$ nm and $l_{e-e} \approx 1-20$ μm . The electron-phonon scattering length depends strongly on temperature. For a typical copper wire $l_{e-ph} \approx 21$ μm at 1 K but at 100 mK we already have $l_{e-ph} \approx 670$ μm .¹ In other metals these length scales are of the same order of magnitude. The superconducting island in the middle is assumed to have small dimensions so that $L \ll l_{e-e}, l_{e-ph}$, leading to weak energy relaxation via inelastic scattering. As shown in the following, in this case it is possible to drive the electron energy distribution of the island out of equilibrium by quasiparticle injection from the superconducting leads. The degree of nonequilibrium of the island can then be probed, for instance, by measuring the supercurrent driven through the island via an additional

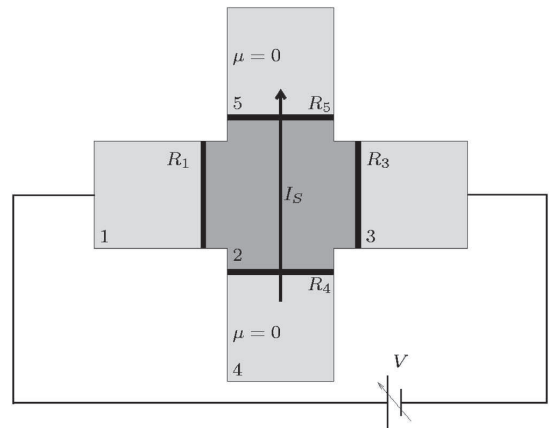


FIG. 1. Scheme of the SISIS structure studied in this work. The superconducting island (2) in the middle is connected with tunnel contacts to four large superconducting leads (1, 3, 4, and 5). The control line is biased with voltage V , which controls the energy distribution on the island. A supercurrent I_S is driven across the island from lead 4 to lead 5, and its magnitude depends on the distribution function on the island. Each SIS junction is a tunnel contact of resistance R_i .

SISIS line. The leads are assumed to remain in thermal equilibrium due to their large dimensions. We further assume that the resistances of the tunnel contacts are large compared to the normal-state resistance of the superconducting island. This allows us to use the tunnel Hamiltonian approach, in which each region has spatially constant, separate energy distributions, independent of the directions of the momenta.

III. FORMALISM

A. Green's functions in SISIS structure

We use the quasiclassical Keldysh Green's function formalism together with the tunnel Hamiltonian model in describing our system. It has previously been successfully applied to hybrid structures with normal metal and superconducting islands.^{10,9} The quasiclassical Green's functions in Nambu space can be written in a matrix form as

$$\hat{g} = \begin{pmatrix} g & f \\ -f^\dagger & \bar{g} \end{pmatrix}, \quad (1)$$

where \hat{g} is either the retarded (advanced), $\hat{g}^{R(A)}$, or Keldysh, \hat{g}^K , Green's function. In the tunnel Hamiltonian model Green's functions are isotropic with respect to the directions of the momenta. In this case the retarded (advanced) functions satisfy the steady-state Usadel equations^{9,11} and Kupriyanov-Lukichev¹² boundary conditions with solutions

$$g^{R(A)} = -\bar{g}^{R(A)} = \pm \frac{E \pm i\gamma}{\sqrt{(E \pm i\gamma)^2 - (|\Delta| \pm i\delta)^2}},$$

$$f^{R(A)} = f^{\dagger R(A)} = \pm \frac{|\Delta| \pm i\delta}{\sqrt{(E \pm i\gamma)^2 - (|\Delta| \pm i\delta)^2}}. \quad (2)$$

Here Δ is the superconducting order parameter, $\gamma = \sum_j \eta_j g_j^{R(A)}$, and $\delta = \sum_j \eta_j f_j^{R(A)}$. The index j runs over the other parts of the structure that are connected with tunnel contacts to the region in question. The characteristic tunneling rate η between superconductors is defined as $\eta_j = (4\nu e^2 \Omega R_j)^{-1}$, where ν is the normal-state density of states at the Fermi level and Ω is the volume of the island. In the tunneling limit $\eta \ll \Delta$ and we may neglect the exact forms of γ and δ and instead use some constant γ and δ in the numerical simulations. Below, we choose $\gamma = 10^{-4}$ and $\delta = 10^{-5}$. This value of γ has been experimentally verified in Ref. 2. The Keldysh Green's function for the system can be written with the standard parametrization as

$$\hat{g}^K = \hat{g}^R(f_L + \hat{\tau}_3 f_T) - (f_L + \hat{\tau}_3 f_T) \hat{g}^A, \quad (3)$$

where $\hat{\tau}_3$ is the third Pauli spin matrix. Here we have also used the odd- and even-in- E parts of the distribution function:

$$f_L(E) = -f(E) + f(-E),$$

$$f_T(E) = 1 - f(-E) - f(E).$$

The full distribution function can be recovered with $2f(E) = 1 - f_L(E) - f_T(E)$. We also define

$$g^{(-)} = \text{Re } g^R = \frac{1}{2}(g^R - g^A),$$

$$f^{(-)} = \text{Re } f^R = \frac{1}{2}(f^R - f^A),$$

$$f^{(+)} = \text{Im } f^R = \frac{1}{2i}(f^R + f^A).$$

The functions $f^{(+)}$ and $g^{(-)}$ are even in E and $f^{(-)}$ is odd. The density of states is given by $g^{(-)}$. The odd and even parts of the nonequilibrium distribution function can now be found from the kinetic equations presented in Ref. 9. The resulting equations are

$$-4J_1 \nu_2 e^2 \Omega_2 = g_{2,E}^{(-)} G_1 \{ g_{1,E+\mu_1}^{(-)} (f_{L2} + f_{T2} - f_{L1} - f_{T1}) + g_{1,E-\mu_1}^{(-)} (f_{L2} - f_{T2} - f_{L1} + f_{T1}) \} + g_{2,E}^{(-)} G_3 \{ g_{3,E+\mu_3}^{(-)} (f_{L2} + f_{T2} - f_{L3} - f_{T3}) + g_{3,E-\mu_3}^{(-)} (f_{L2} - f_{T2} - f_{L3} + f_{T3}) \}, \quad (4)$$

$$(8|\Delta_2| f_{T2} f_2^{(+)} - 4J_2) \nu_2 e^2 \Omega_2 = g_{2,E}^{(-)} G_1 \{ g_{1,E+\mu_1}^{(-)} (f_{L2} + f_{T2} - f_{L1} - f_{T1}) + g_{1,E-\mu_1}^{(-)} (-f_{L2} + f_{T2} + f_{L1} - f_{T1}) \} + g_{2,E}^{(-)} G_3 \{ g_{3,E+\mu_3}^{(-)} (f_{L2} + f_{T2} - f_{L3} - f_{T3}) + g_{3,E-\mu_3}^{(-)} (-f_{L2} + f_{T2} + f_{L3} - f_{T3}) \}, \quad (5)$$

where $G_i = 1/R_i$ are the conductances of the tunnel contacts, μ_i are the chemical potentials of the regions i , and J_i are the collision integrals for the energy relaxation.

B. Order parameter and currents

The pair potential in the central island must be solved self-consistently from the equation

$$|\Delta_2| = \frac{\lambda}{2} \int_{-E_C}^{E_C} dE f_{L2} f_E^{(-)}, \quad (6)$$

where E_C is the BCS cutoff energy and λ is the electron-electron interaction parameter. When a SIS junction is not biased with an external voltage, the supercurrent flowing across the junction is given by

$$I_S^{2 \rightarrow 4} = -\frac{1}{2eR_4} \int_{-\infty}^{\infty} dE \{ (f_{L2} f_2^{(-)} f_4^{(+)} + f_{L4} f_4^{(-)} f_2^{(+)}) \sin(\chi_4 - \chi_2) + (f_{T2} - f_{T4}) [g_2^{(-)} g_4^{(-)} + f_2^{(+)} f_4^{(+)} \cos(\chi_4 - \chi_2)] \}. \quad (7)$$

The first part of the equation multiplying the sine term represents the usual dc Josephson relation where $\chi_{2,4}$ are the macroscopic phases of the respective superconductors. The term $f_2^{(-)} f_4^{(+)}$ is finite only when $\Delta_2 < E < \Delta_4$ whereas the term $f_4^{(-)} f_2^{(+)}$ is finite when $\Delta_4 < E < \Delta_2$. The second part in Eq. (7) usually vanishes because $f_T = 0$ in quasiequilibrium. If a finite

charge imbalance develops on the island, f_{T2} deviates from zero, and the second part contributes to the current as well.

If a voltage is applied across the junction the phase difference begins to evolve in time and the supercurrent averages to zero. In this case only the tunneling of quasiparticles contributes to the current, so that we have

$$I^{1 \rightarrow 2} = -\frac{1}{4eR_1} \int_{-\infty}^{\infty} dE \{ g_{1,E+\mu}^{(-)} g_{2,E}^{(-)} (f_{L2} + f_{T2} - f_{L1} - f_{T1}) + g_{1,E-\mu}^{(-)} g_{2,E}^{(-)} (-f_{L2} + f_{T2} + f_{L1} - f_{T1}) \}. \quad (8)$$

The quasiparticles tunneling through the junction also carry heat. The energy current is

$$I_E^{1 \rightarrow 2} = -\frac{1}{4e^2 R_1} \int_{-\infty}^{\infty} dE E \{ g_{1,E+\mu}^{(-)} g_{2,E}^{(-)} (f_{L2} + f_{T2} - f_{L1} - f_{T1}) + g_{1,E-\mu}^{(-)} g_{2,E}^{(-)} (f_{L2} - f_{T2} - f_{L1} + f_{T1}) \}, \quad (9)$$

which is used in determining the electron temperature in quasiequilibrium.

C. Energy relaxation

In practice the inelastic scattering is never completely absent. At low temperatures the most relevant relaxation mechanism is electron-electron scattering, which can be included with e - e collision integrals. We may also study cases where the dimensions of the island are no longer significantly smaller than the electron-electron scattering length, i.e., $L \lesssim l_{e-e} \ll l_{e-ph}$. The collision integral for a screened Coulomb interaction in a diffusive wire is known¹³ and has been used in the analysis of a SINIS system.⁶ It is strictly valid only for a normal metal island, however. To get a qualitative picture of the changes due to superconductivity in energy relaxation, we apply instead a collision integral where the structure of the Nambu space has been taken into account. In the clean limit the potential of a distant electron is completely screened by all other electrons in the superconductor and the electron-electron interaction can be approximated by a point interaction. In this case the potential may be modeled with a δ function $V(\mathbf{r}) = \nu_2 \lambda_{ee} \delta(\mathbf{r})$ and the collision integral is¹⁴

$$J_1^{(ee)}(E_3) = \kappa \int \int dE_1 dE_2 \{ (g_{E_1}^{(-)} g_{E_2}^{(-)} - f_{E_1}^{(-)} f_{E_2}^{(-)}) (g_{E_3}^{(-)} g_{E_3}^{(-)} + f_{E_3}^{(-)} f_{E_3}^{(-)}) \times [(1 - f_E) f_{E_1} f_{E_2} f_{E_3} - f_E (1 - f_{E_1}) (1 - f_{E_2}) \times (1 - f_{E_3})] \}, \quad (10)$$

where $\kappa = 4\lambda_{ee}^2 \pi / p_F v_F$, v_F and p_F are the Fermi velocity and momentum, respectively, and the energies satisfy the conservation law $E = E_1 + E_2 + E_3$. The second collision integral $J_2^{(ee)}$ vanishes in a left-right symmetric structure. We note that, because the terms $g_{E_3}^{(-)}$ and $f_{E_3}^{(-)}$ in the kernel of the integral assume very small values when $|E_3| < \Delta$, the collision integral has a very small effect on excitations inside the gap. On the other hand, energy relaxation is strongest for excitations at $|E_3| = \Delta$ due to sharp peaks at the edge of the gap in these same terms.

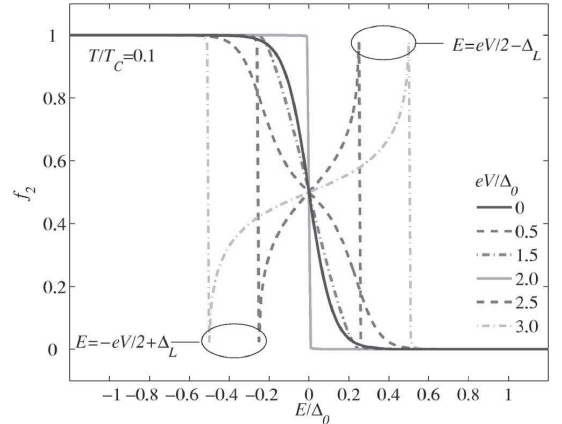


FIG. 2. (Color online) Nonequilibrium distribution function for the superconducting island at $T = 0.1T_C$. The cooling effect reducing the number of excited quasiparticles as the voltage is increased is evident. Here and below we denote $\Delta_0 = \Delta_L(T=0)$ and T_C is the critical temperature of the leads.

IV. RESULTS

A. Full nonequilibrium

We begin by presenting the calculated distribution function along with the order parameter and electric currents for the simplest, namely, left-right symmetric, case, where the tunnel junction resistances are the same and reservoirs 1 and 3 are similar superconductors, i.e., $R_1 = R_3 = R$ and $|\Delta_1| = |\Delta_3| = |\Delta_L|$. When the structure is biased with a voltage V , the conservation of electric current forces the chemical potentials of reservoirs 1 and 3 to $\mu_1 = eV/2$ and $\mu_3 = -eV/2$, respectively.

1. Distribution function

The solution of the kinetic equations (4) and (5) in the absence of energy relaxation ($J_1 = J_2 = 0$) may be written in terms of the full distribution functions as

$$f_2 = \frac{g_{E+\mu}^{(-)} f_1 + g_{E-\mu}^{(-)} f_3}{g_{E+\mu}^{(-)} + g_{E-\mu}^{(-)}}. \quad (11)$$

This form is remarkably simple due to the symmetry of the problem, and it can also be derived by considering the conservation of electric current.¹⁵ The distribution function is plotted in Fig. 2 for various bias voltages at a bath temperature of $0.1T_C$. The critical temperature of the superconductor is $T_C = (1.764k_B)^{-1} \Delta_0$. With a small voltage bias fewer of the states below the Fermi level are occupied whereas the occupation is increased above the Fermi level. This increase in excited quasiparticles can be interpreted as a heating of the island. This anomalous heating effect stems from the assumption of a finite γ in Eq. (2), i.e., from the presence of quasiparticle states within the gap. In the absence of these states, no anomalous heating is observed. Once the voltage is increased above $eV = \Delta_L$, the number of excited quasiparticles on the island begins to decrease due to extraction to

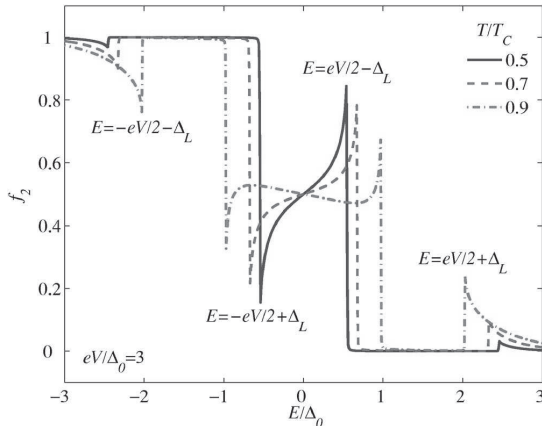


FIG. 3. (Color online) Nonequilibrium distribution function for the superconducting island at various bath temperatures for a voltage $eV/\Delta_0=3$.

states right above the energy gap in the superconducting reservoirs. This cooling effect is discussed in Refs. 1 and 2. In Fig. 3 the distribution function is plotted at higher bath temperatures for a bias voltage $eV/\Delta_0=3$. At these temperatures the reservoirs have more excited quasiparticles above and below the gap, and the small notches at $|E|=eV/2+\Delta_L$ are a result of their injection.

2. Order parameter

In order to measure the degree of nonequilibrium on the island we must look for nonequilibrium-induced effects in some measurable quantities, e.g., the supercurrent through the island. First we calculate the magnitude of the order parameter with the self-consistency equation (6). In general this must be solved numerically. The magnitude of the order parameter of the island as a function of voltage at various bath temperatures is shown in Fig. 4(a). At $T=0.1T_C$ the odd-in- E part of the distribution is effectively unchanged outside the gap, giving the same result as for equilibrium. However, once $eV \geq 2\Delta_L$ the peculiar shape of the distribution makes it possible to have a lower-value solution for the order parameter as well, giving rise to a hysteretic behavior with three solutions. Once the voltage reaches $eV=2(\Delta_2+\Delta_L)$ only the smallest solution, namely, $\Delta_2=0$, is possible. This is due to the fact that the order parameter can never exceed its zero-temperature value. The multivalued behavior of the order parameter can be interpreted as different minima and maxima in the free energy.^{6,15} In this case the largest and smallest values represent minima and the middle value represents a maximum. If we increase the voltage from zero, the system stays in the free-energy minimum corresponding to a superconducting state. Once we enter the hysteretic region, thermal fluctuations may cause the system to jump to the normal state, which is the other free-energy minimum. In the absence of fluctuations, the system finally jumps to the normal state at $eV=2(\Delta_2+\Delta_L)$. If we now proceed by decreasing the voltage, the jump to the superconducting state may again

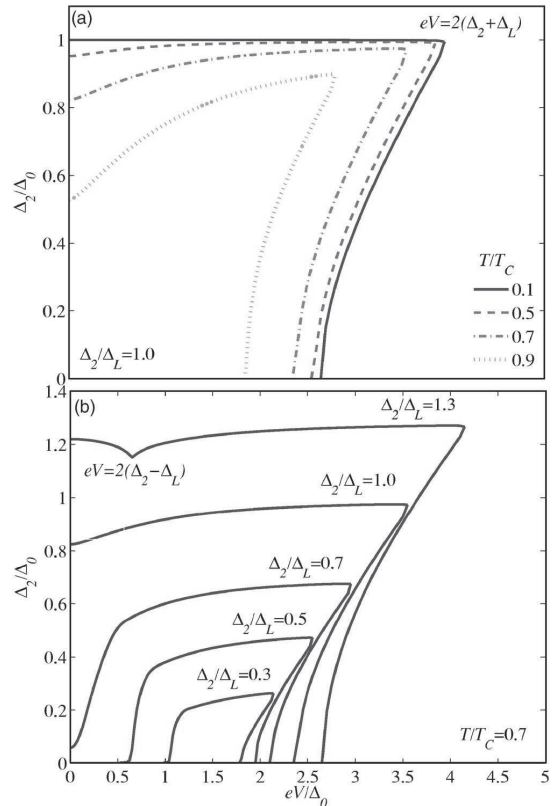


FIG. 4. (Color online) Order parameter as a function of bias voltage at various bath temperatures (a) and ratios Δ_2/Δ_L (b).

occur somewhere in the hysteretic region. Once the voltage is decreased enough, only the superconducting state is possible.

At higher bath temperatures the order parameter is initially in its equilibrium value, but increases along the voltage as the island cools. In Fig. 4(b) the order parameter is shown at $T=0.7T_C$ but for different zero-temperature ratios $\Delta_2/\Delta_L = T_C/T_C$. For ratios $\Delta_2/\Delta_L < 0.7$, the island is initially in the normal state because the bath temperature is above its critical temperature. Upon increasing the voltage, the island turns superconducting once the electron distribution has features sharp enough to support an energy gap.

3. Electric currents

Now we examine the effect that the magnitude of the order parameter has on the electric current driven through the island. In light of the results in the previous subsection the measurements should be made at relatively high temperature in order to fully bring out the variation in the energy gap. Choosing a setup with a lower Δ_2/Δ_L ratio enables us to use a lower absolute temperature and thereby also minimize the electron-phonon relaxation, because the power injected into the phonons depends on temperature as T^5 .¹⁶ The supercur-

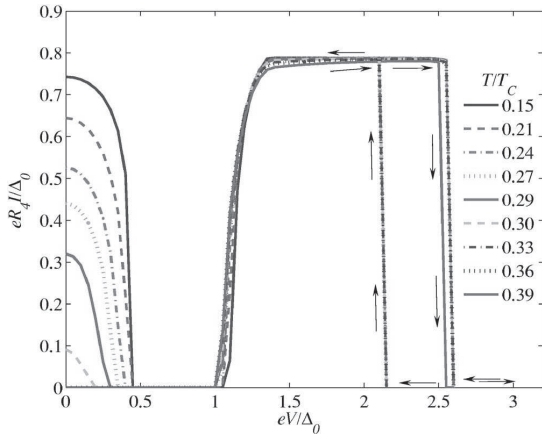


FIG. 5. (Color online) Supercurrent through the island in full nonequilibrium as a function of bias voltage at various bath temperatures with a ratio $\Delta_2/\Delta_L=0.3$. The arrows indicate the direction the curve is traced when the bias voltage is varied. Thermal fluctuations may cause the discontinuous jump to occur somewhere in between the two extremes shown in the figure. The system is assumed symmetric, i.e., $R_1=R_3=R_4=R_5$ and $\Delta_4=\Delta_5=\Delta_L$.

rent through the island is calculated with Eq. (7) and it is presented in Fig. 5 for various temperatures assuming a ratio $\Delta_2/\Delta_L=0.3$, which corresponds roughly to the Ti-Al combination. When the bath temperature is lower than the critical temperature of the island, the initial heating effect with low bias voltages is evident. In the cooling regime the bath temperature has a negligible effect on the magnitude of the supercurrent. The hysteresis of the order parameter carries over to the supercurrent but no π state is observed. It is illustrative to compare these to the corresponding results in quasiequilibrium, where the high frequency of electron-electron collisions forces the quasiparticles on the island to assume a Fermi distribution. The electron temperature in quasiequilibrium can be obtained by demanding that the energy current in Eq. (9) to the island vanishes (we also neglect the contribution of electron-phonon interaction to the energy current). The supercurrent in quasiequilibrium is shown in Fig. 6. In quasiequilibrium the heating effect is absent and the island cools even with low voltages, resulting in an increase of the supercurrent. Superconductivity is lost once the voltage exceeds $eV=2(\Delta_2+\Delta_L)$, just as in full nonequilibrium. The falling edge here is not hysteretic, however. A further means to probe the degree of nonequilibrium is to voltage bias the second SISIS line as well and measure the energy gap from the $I-V$ curve. The quasiparticle current flowing through the probe junction in this case may be calculated with Eq. (8). The resulting $I-V$ curve does not differ from its equilibrium shape, in which the current has a discontinuous jump at $eV=2(\Delta_2+\Delta_L)$.¹⁷ The value of Δ_2 and its hysteresis change the voltage at which the jump is observed, however.

B. Nonequilibrium with energy relaxation

When the energy relaxation due to inelastic electron-electron scattering is taken into account, we are no longer

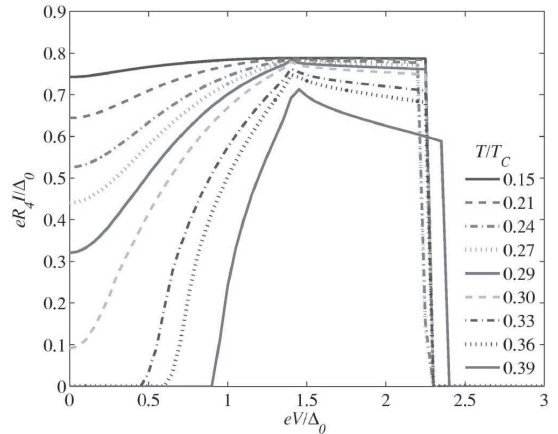


FIG. 6. (Color online) Supercurrent through the island in quasiequilibrium as a function of bias voltage with parameters identical to those of the full nonequilibrium case presented in Fig. 5.

able to obtain an explicit expression for f_2 . In the left-right symmetric case we must instead solve the resulting integral equation

$$f_2 = \frac{g_{E+\mu}^{(-)} f_1 + g_{E-\mu}^{(-)} f_3 + (e^2 \nu_2 \Omega_2 R_1 / g_{2,E}^{(-)}) J_1^{(e)} [f_2]}{g_{E+\mu}^{(-)} + g_{E-\mu}^{(-)}}. \quad (12)$$

The relaxation strength can be adjusted by varying the parameter $\mathcal{K}_{coll} = \kappa e^2 \nu_2 \Omega_2 R_1$. The distribution function calculated for various values of \mathcal{K}_{coll} is shown in Fig. 7. The energy distribution gradually relaxes toward a Fermi distribution upon increasing the strength of the relaxation. The influence of inelastic scattering to the supercurrent is shown in Fig. 8 for a structure consisting entirely of one type of a superconductor. The enhancement of superconductivity is suppressed as the electron-electron collisions drive the electron temperature of the central island toward quasiequilibrium. With the strongest relaxation the cooling effect is completely lost and the supercurrent drops smoothly to zero as the voltage is increased. With the two largest strengths of

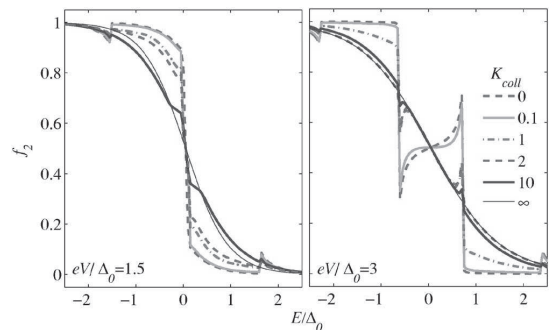


FIG. 7. (Color online) Distribution function for the superconducting island at $eV/\Delta_0=1.5$ (left) and 3 (right) for various \mathcal{K}_{coll} with $T=0.7T_C$. $\mathcal{K}_{coll}=\infty$ corresponds to quasiequilibrium.

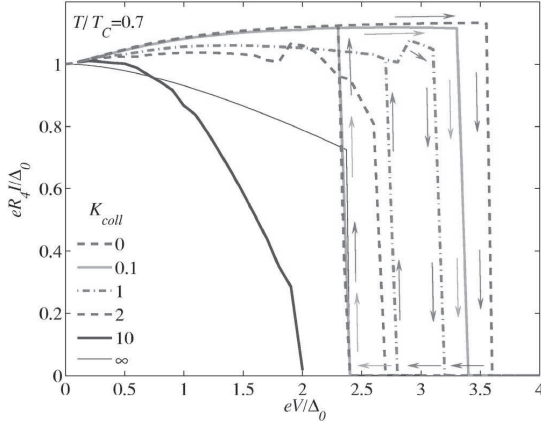


FIG. 8. (Color online) Supercurrent through the island as a function of voltage for various \mathcal{K}_{coll} with $T=0.7T_C$. For the hysteretic curves the arrows indicate the direction the curve is traced when the bias voltage is varied.

relaxation the hysteresis is lost as well. At larger voltages the supercurrent is a nonmonotonic function of \mathcal{K}_{coll} , as the supercurrent in quasiequilibrium ($\mathcal{K}_{coll}=\infty$) is significantly larger than with moderate relaxation. This can also be seen in the left part of Fig. 7, where the distribution function in quasiequilibrium is sharper compared to the distribution with $\mathcal{K}_{coll}=10$. This sharpness leads directly to a larger supercurrent. The curves with $\mathcal{K}_{coll}=1$ and $\mathcal{K}_{coll}=2$ show a small jump in the supercurrent at voltages over $eV=2$. This corresponds to a transition above which $\Delta_4 > \Delta_2$. By choosing a setup where leads 4 and 5 have a different energy gap from the rest of the system, this peak could be seen at different voltages.

C. Asymmetric structure

Let us now examine an asymmetric situation, where $R_1 \neq R_3$ or $\Delta_1 \neq \Delta_3$. By solving the kinetic equations (4) and (5) without relaxation we obtain quite lengthy expressions for the odd and even parts of the distribution function

$$\begin{aligned}
 Df_{L2} = & 4e^2 f_2^{(+)} \nu_2 \Omega_2 |\Delta_2| \{ G_1 [(f_{L1} - f_{T1}) g_{1,E-\mu_1}^{(-)} \\
 & + (f_{L1} + f_{T1}) g_{1,E+\mu_1}^{(-)}] + G_3 [(f_{L3} - f_{T3}) g_{3,E-\mu_3}^{(-)} \\
 & + (f_{L3} + f_{T3}) g_{3,E+\mu_3}^{(-)}] \} - g_{2,E}^{(-)} \{ G_1 [2f_{L1} G_1 g_{1,E-\mu_1}^{(-)} \\
 & + (f_{L1} + f_{L3} + f_{T1} - f_{T3}) G_3 g_{3,E-\mu_3}^{(-)}] g_{1,E+\mu_1}^{(-)} \\
 & + G_3 [2f_{L3} G_3 g_{3,E-\mu_3}^{(-)} + (f_{L1} + f_{L3} - f_{T1} + f_{T3}) \\
 & \times G_1 g_{1,E-\mu_1}^{(-)}] g_{3,E+\mu_3}^{(-)} \}, \\
 Df_{T2} = & -g_{2,E}^{(-)} \{ G_1 [2f_{T1} G_1 g_{1,E-\mu_1}^{(-)} + (f_{L1} - f_{L3} + f_{T1} + f_{T3}) \\
 & \times G_3 g_{3,E-\mu_3}^{(-)}] g_{1,E+\mu_1}^{(-)} + G_3 [2f_{T3} G_3 g_{3,E-\mu_3}^{(-)} \\
 & + (-f_{L1} + f_{L3} + f_{T1} + f_{T3}) G_1 g_{1,E-\mu_1}^{(-)}] g_{3,E+\mu_3}^{(-)} \}, \quad (13)
 \end{aligned}$$

where

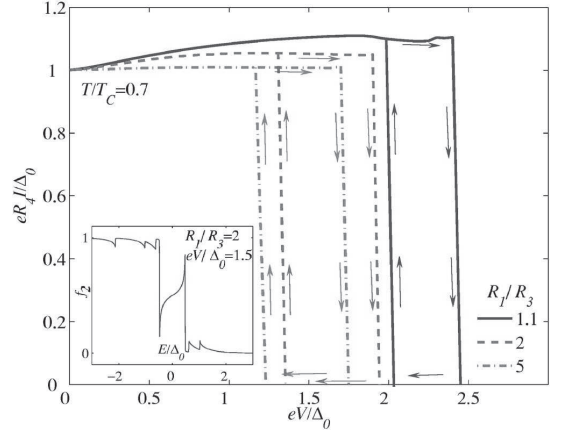


FIG. 9. (Color online) Supercurrent through the island as a function of voltage for different degrees of asymmetry in the SISIS control line. The arrows indicate the direction the curve is traced when the bias voltage is varied. The inset shows the distribution function on the island for a ratio $R_1/R_3=2$ at $eV/\Delta_0=1.5$. The distribution function exhibits small asymmetry due to finite f_T as can be seen by the additional notch at negative energies.

$$\begin{aligned}
 D = & 4e^2 f_2^{(+)} \nu_2 \Omega_2 |\Delta_2| [G_1 (g_{1,E-\mu_1}^{(-)} + g_{1,E+\mu_1}^{(-)}) \\
 & + G_3 (g_{3,E-\mu_3}^{(-)} + g_{3,E+\mu_3}^{(-)})] - 2g_{2,E}^{(-)} (G_1 g_{1,E-\mu_1}^{(-)} + G_3 g_{3,E-\mu_3}^{(-)}) \\
 & \times (G_1 g_{1,E+\mu_1}^{(-)} + G_3 g_{3,E+\mu_3}^{(-)}).
 \end{aligned}$$

The distribution functions depend on the volume, energy gap, and normal-state density of states at the Fermi level, but these can be included in dimensionless constants of the type $G/|\Delta| \nu \Omega e^2$. In the asymmetric case the potentials μ_1 and μ_3 must be chosen such that the electrical current is conserved. This implies the vanishing of the total net current into the island, i.e., $I^{1 \rightarrow 2} = I^{2 \rightarrow 3}$ calculated with Eq. (8).

The supercurrent for $\chi_4 - \chi_2 = \pi/2$ and different ratios R_1/R_3 is shown in Fig. 9. In an asymmetric structure the magnitude of the order parameter seems to be close to its value in the symmetric case with a voltage of $eV = 2 \max(|\mu_1|, |\mu_3|)$. This is reasonable because the distribution function in the region $|E| > \max(\Delta_1 + |\mu_1|, \Delta_3 + |\mu_3|)$ is similar to the distribution in the symmetric structure as shown in the inset. Superconductivity is lost once $|\mu_1| > \Delta_2 + \Delta_1$ or $|\mu_3| > \Delta_2 + \Delta_3$. With high asymmetry ratios the potentials differ very much from $\pm eV/2$ and superconductivity is lost at a lower bias voltage compared to the symmetric structure. Also the hysteretic region is evident.

Because the charge imbalance function f_T is finite in an asymmetric system, also the latter part of Eq. (7) may contribute, depending on the phase difference between the superconductors. Its magnitude can be investigated by setting the phase difference to zero. In this case the electric current is significantly smaller, of the order of $10^{-3} eR_4 I / \Delta_0$, and mostly due to quasiparticle current induced by the charge imbalance. The charge imbalance leads to a difference in

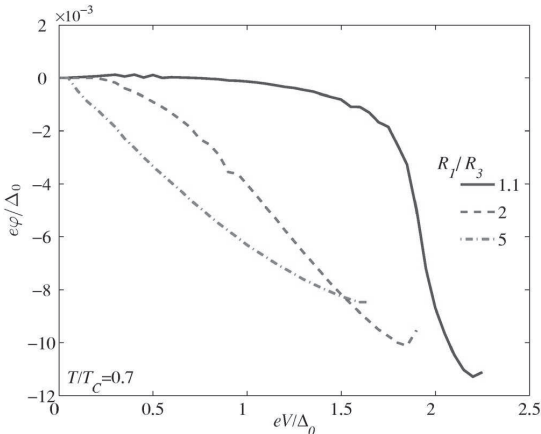


FIG. 10. (Color online) Potential difference between quasiparticles and the condensate for different degrees of asymmetry in the SIS control line.

chemical potentials between quasiparticles and the condensate. The potential difference is given by⁹

$$e\varphi = - \int_{-\infty}^{\infty} \frac{dE}{2} f_{T2} g_2^{(-)}. \quad (14)$$

This quantity is shown in Fig. 10 for the superconducting regime. The quasiparticle current depends linearly on this potential difference. The equation for the supercurrent also seems to imply a $\cos(\Delta\chi)$ dependence in the supercurrent. This deviation from the dc Josephson relation is negligible, however, because the integral over the supercurrent term $f_2^{(+)} J_4^{(+)}$ is three orders of magnitude smaller than over the quasiparticle current term $g_2^{(-)} g_4^{(-)}$.

V. DISCUSSION

According to our results there are several measurable features present in a nonequilibrium, all-superconducting, tun-

nel structure. The initial electron heating is seen as a strong suppression in superconductivity of the central island when the tunnel structure is biased with a low voltage. This is observable when the bath temperature is slightly below the critical temperature of the central island but well below the critical temperature of the superconducting leads. The nonequilibrium cooling effect together with the destruction of superconductivity at $eV=2(\Delta_2+\Delta_L)$ should be observable with a wide range of configurations. The accompanying hysteresis with low or nonexisting relaxation can be seen in the supercurrent as well. The magnitude of the energy gap could be directly measured with a quasiparticle current probe, where the jump in the current happens at a probe voltage of $eV=2(\Delta_2+\Delta_L)$.

Due to hysteresis the application of this structure as a transistor is unfeasible in states far from equilibrium. With moderate to strong relaxation the hysteresis is absent and does not hamper transistorlike operation. The sharp current-voltage characteristics giving rise to high differential current gain are lost with the strongest relaxation, however. If actual power gain were to be achieved, the Josephson junctions have to be operated in the dissipative regime and coupling to the environment should be taken into account in the calculations.

Small asymmetries of the order of 10% in the system do not give rise to qualitatively different behavior. Asymmetries larger than that begin to develop charge imbalance in the central island, leading to different chemical potentials for the superconducting condensate and quasiparticle excitations. This potential difference can be observed in the quasiparticle current flowing to the island from both reservoirs 4 and 5, when the phase difference across the Josephson junctions vanishes.

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